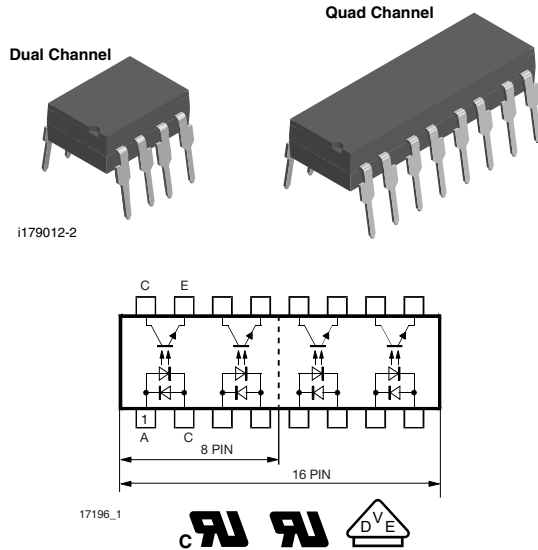


## Optocoupler, Phototransistor Output, AC Input (Dual, Quad Channel)



### FEATURES

- Extra low coupling capacity - typical 0.2 pF
- High common mode rejection
- Low temperature coefficient of CTR
- Rated impulse voltage (transient overvoltage)  $V_{IOTM} = 10$  kV peak
- Isolation test voltage (partial discharge test voltage)  $V_{pd} = 1.6$  kV peak
- Rated isolation voltage (RMS includes DC)  $V_{IOWM} = 600 V_{RMS}$
- Rated recurring peak voltage (repetitive)  $V_{IORM} = 848 V_{peak}$
- Thickness through insulation  $\geq 0.4$  mm
- Creepage current resistance according to VDE 0303/IEC 60112 comparative tracking index:  $CTI \geq 175$
- Compliant to RoHS Directive to 2002/95/EC and in accordance WEEE 2002/96/EC



**RoHS**  
COMPLIANT

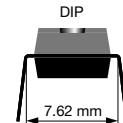
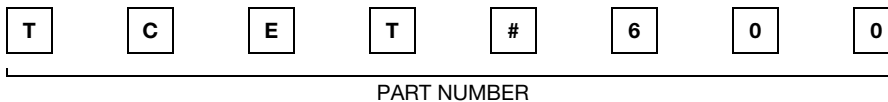
### DESCRIPTION

The TCET2600, TCET4600 consists of a phototransistor optically coupled to 2 gallium arsenide infrared-emitting diodes in 8 pin or 16 lead plastic dual in line package.

### AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-2 (VDE 0884)  
DIN EN 60747-5-5 (pending)
- FIMKO

### ORDERING INFORMATION



AGENCY CERTIFIED/ PACKAGE	CTR (%)
	$\pm 5$ mA
<b>UL, cUL, VDE, FIMKO</b>	<b>20 to 300</b>
DIP-8, dual channel	TCET2600
DIP-16, quad channel	TCET4600

### ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup> ( $T_{amb} = 25$ °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		$V_R$	6	V
Forward current		$I_F$	$\pm 60$	mA
Forward surge current	$t_p \leq 10 \mu s$	$I_{FSM}$	$\pm 1.5$	A
Power dissipation		$P_{diss}$	100	mW
Junction temperature		$T_j$	125	°C

<b>ABSOLUTE MAXIMUM RATINGS (1)</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>OUTPUT</b>				
Collector emitter voltage		$V_{CEO}$	70	V
Emitter collector voltage		$V_{ECO}$	7	V
Collector current		$I_C$	50	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10\text{ ms}$	$I_{CM}$	100	mA
Power dissipation		$P_{diss}$	150	mW
Junction temperature		$T_j$	125	$^{\circ}\text{C}$
<b>COUPLER</b>				
Isolation test voltage (RMS)	$t = 1\text{ s}$	$V_{ISO}$	5300	$V_{RMS}$
Isolation voltage		$V_{IORM}$	890	$V_P$
Total power dissipation		$P_{tot}$	250	mW
Operating ambient temperature range		$T_{amb}$	- 55 to + 100	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	- 55 to + 150	$^{\circ}\text{C}$
Soldering temperature (2)	2 mm from case, $t \leq 10\text{ s}$	$T_{sld}$	260	$^{\circ}\text{C}$

### Notes

- (1) Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.
- (2) Refer to wave profile for soldering conditions for through hole devices.

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward voltage	$I_F = \pm 50\text{ mA}$	$V_F$		1.25	1.6	V
Junction capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$	$C_j$		50		pF
<b>OUTPUT</b>						
Collector emitter voltage	$I_C = 100\text{ }\mu\text{A}$	$V_{CEO}$	70			V
Emitter collector voltage	$I_E = 100\text{ }\mu\text{A}$	$V_{ECO}$	7			V
Collector dark current	$V_{CE} = 20\text{ V}, I_F = 0\text{ A}, E = 0$	$I_{CEO}$			100	nA
<b>COUPLER</b>						
Collector emitter saturation voltage	$I_F = 10\text{ mA}, I_C = 1\text{ mA}$	$V_{CEsat}$			0.3	V
Cut-off frequency	$V_{CE} = 5\text{ V}, I_F = 10\text{ mA}, R_L = 100\text{ }\Omega$	$f_c$		100		kHz
Coupling capacitance	$f = 1\text{ MHz}$	$C_k$		0.3		pF

### Note

- Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

<b>CURRENT TRANSFER RATIO</b>						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_C/I_F$	$V_{CE} = 5\text{ V}, I_F = \pm 5\text{ mA}$	CTR	20		300	%

MAXIMUM SAFETY RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward current		$I_F$			275	mA
<b>OUTPUT</b>						
Power dissipation		$P_{diss}$			400	mW
<b>COUPLER</b>						
Rated impulse voltage		$V_{IOTM}$			10	kV
Safety temperature		$T_{si}$			175	°C

**Note**

- According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Partial discharge test voltage - routine test	100 %, $t_{test} = 1$ s	$V_{pd}$	1.669			kV
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60$ s, $t_{test} = 10$ s, (see figure 2)	$V_{IOTM}$	10			kV
		$V_{pd}$	1.424			kV
Insulation resistance	$V_{IO} = 500$ V	$R_{IO}$	$10^{12}$			$\Omega$
	$V_{IO} = 500$ V, $T_{amb} = 100$ °C	$R_{IO}$	$10^{11}$			$\Omega$
	$V_{IO} = 500$ V, $T_{amb} = 150$ °C (construction test only)	$R_{IO}$	$10^9$			$\Omega$

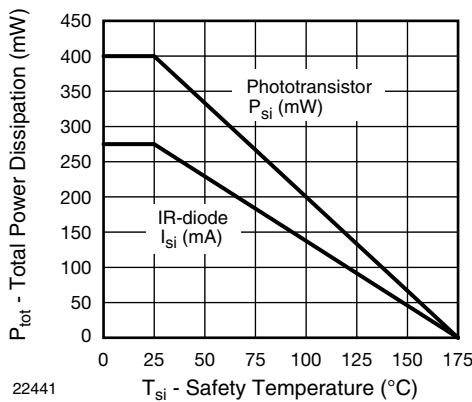


Fig. 1 - Derating Diagram

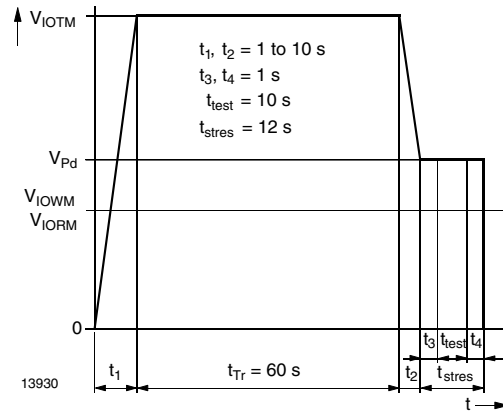
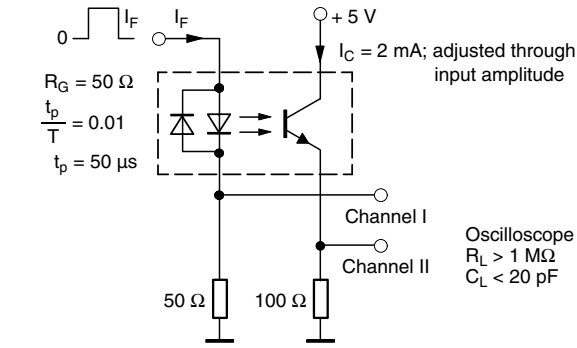


Fig. 2 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_d$		3		$\mu\text{s}$
Rise time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_r$		3		$\mu\text{s}$
Fall time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_f$		4.7		$\mu\text{s}$
Storage time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_s$		0.3		$\mu\text{s}$
Turn-on time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_{on}$		6		$\mu\text{s}$
Turn-off time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 3)	$t_{off}$		5		$\mu\text{s}$
Turn-on time	$V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ , (see figure 4)	$t_{on}$		9		$\mu\text{s}$
Turn-off time	$V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ , (see figure 4)	$t_{off}$		10		$\mu\text{s}$



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Fig. 3 - Test Circuit, Non-Saturated Operation

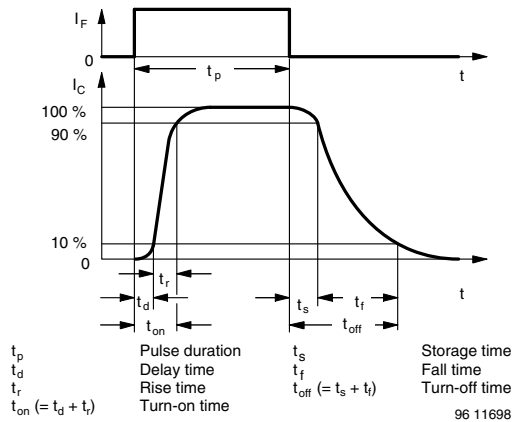
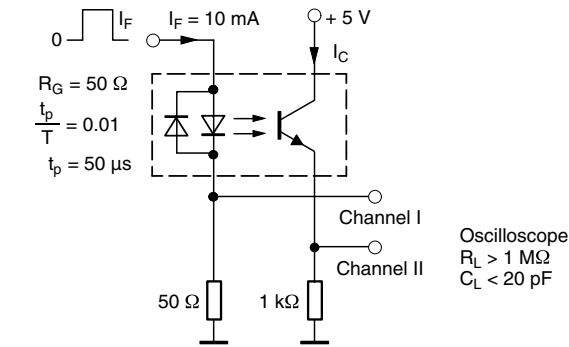


Fig. 5 - Switching Times



13344

Fig. 4 - Test Circuit, Saturated Operation

### TYPICAL CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

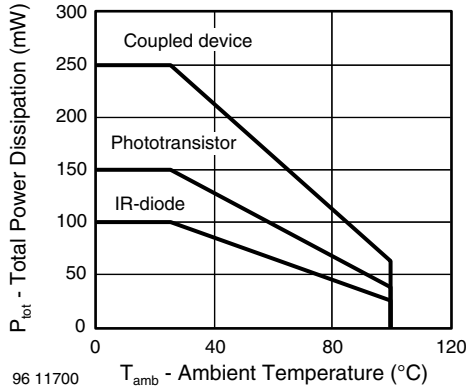


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

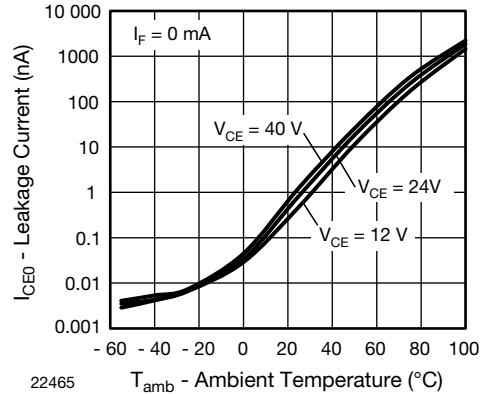


Fig. 9 - Leakage Current vs. Ambient Temperature

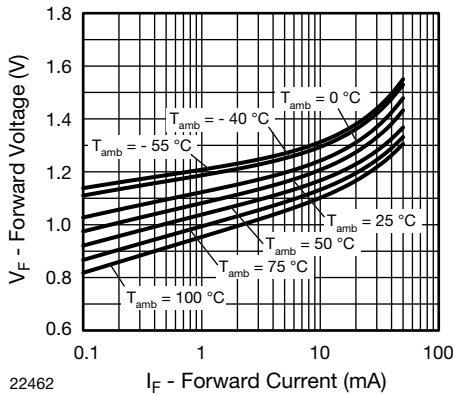


Fig. 7 - Forward Current vs. Forward Voltage

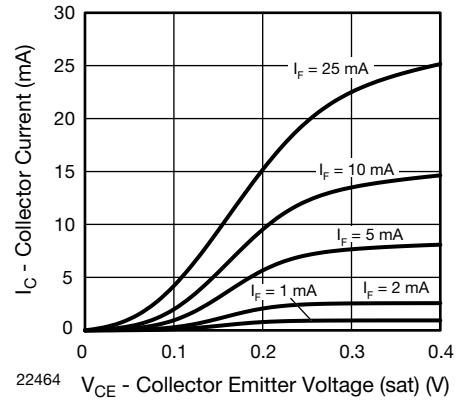


Fig. 10 - Collector Current vs. Collector Emitter Voltage (sat)

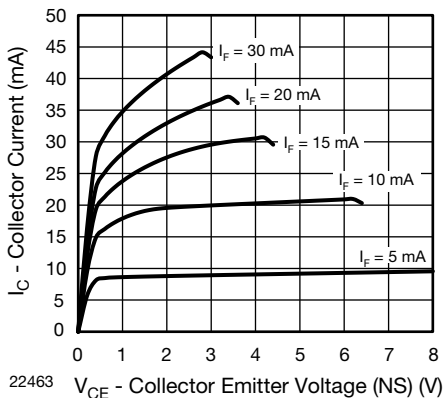


Fig. 8 - Collector Current vs. Collector Emitter Voltage (NS)

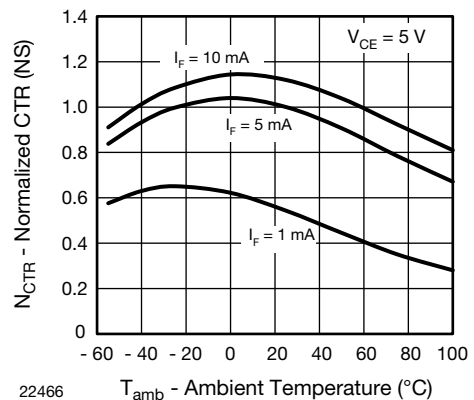


Fig. 11 - Normalized CTR (NS) vs. Ambient Temperature

# TCET2600, TCET4600



Vishay Semiconductors Optocoupler, Phototransistor Output,  
AC Input (Dual, Quad Channel)

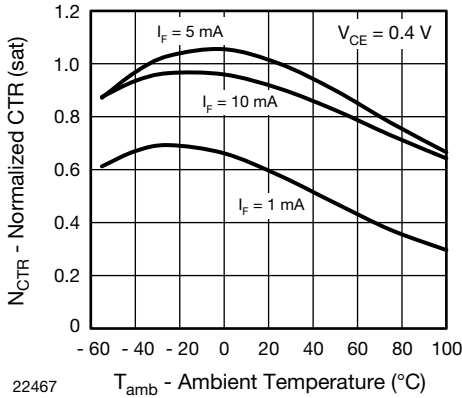


Fig. 12 - Normalized CTR (sat) vs. Ambient Temperature

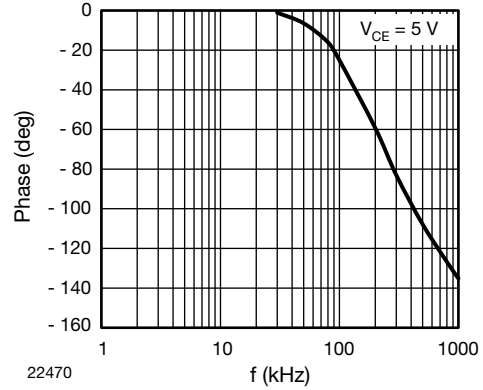


Fig. 15 -  $F_{CTR}$  vs. Phase Angle

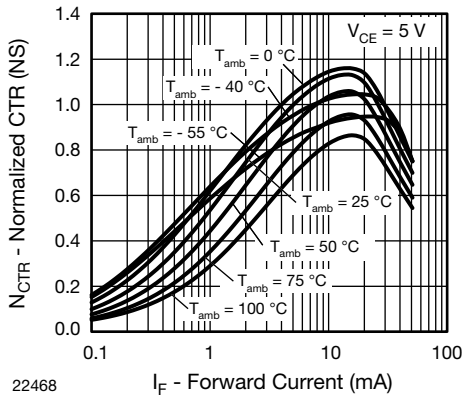


Fig. 13 - Normalized CTR (NS) vs. Forward Current

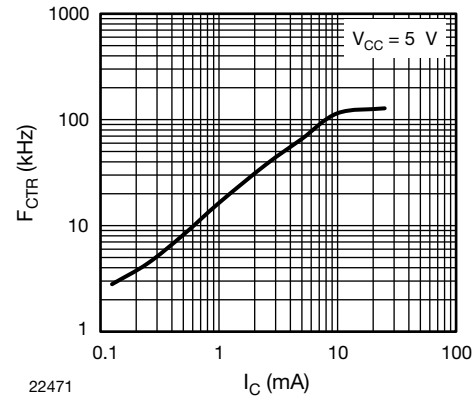


Fig. 16 -  $F_{CTR}$  vs.  $I_C$

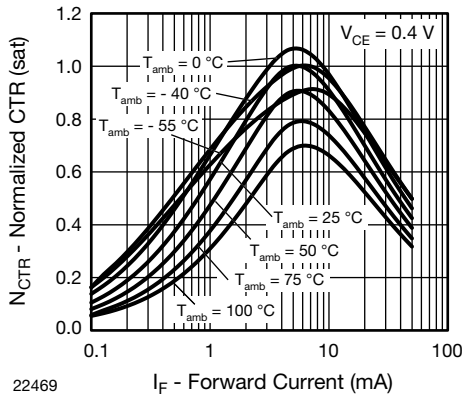


Fig. 14 - Normalized CTR (sat) vs. Forward Current

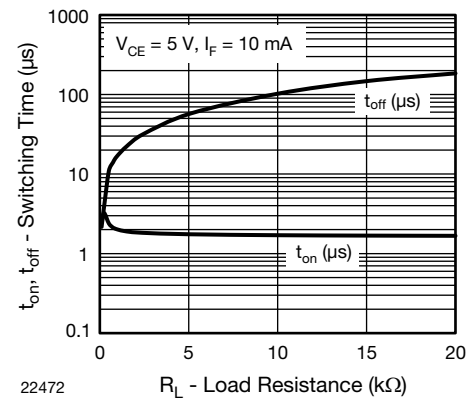


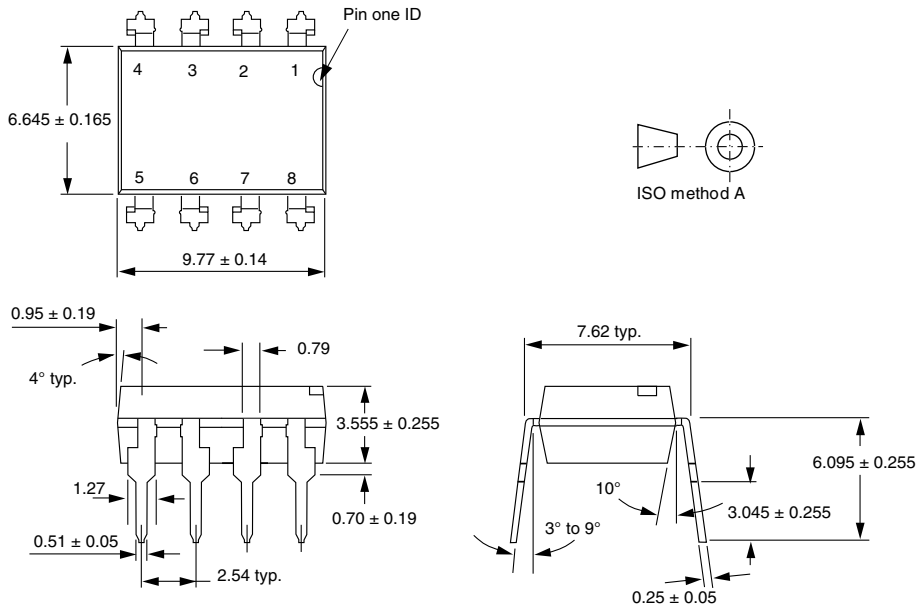
Fig. 17 - Switching Time vs. Load Resistance



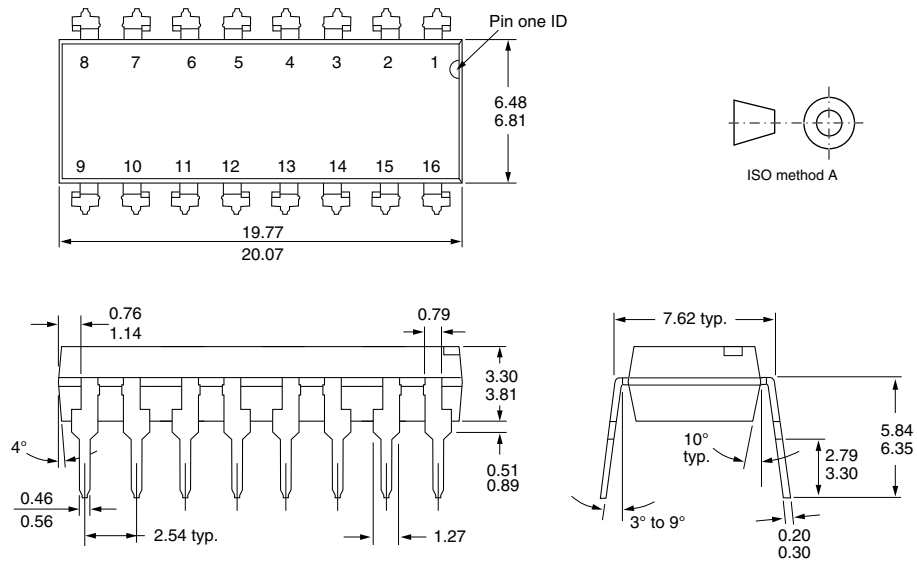
# TCET2600, TCET4600

Optocoupler, Phototransistor Output, Vishay Semiconductors  
AC Input (Dual, Quad Channel)

## PACKAGE DIMENSIONS in millimeters

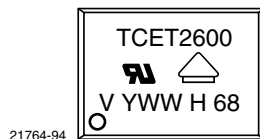


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## PACKAGE MARKING





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